

January 2014

FDBL86210 F085

N-Channel Power Trench[®] MOSFET 150V, 169A, $6.3m\Omega$

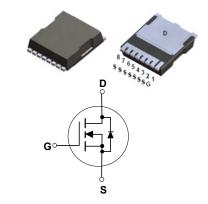
Features

- Typ $r_{DS(on)}$ = 5m Ω at V_{GS} = 10V, I_D = 80A
- Typ $Q_{q(tot)}$ = 70nC at V_{GS} = 10V, I_D = 80A
- UIS Capability
- RoHS Compliant
- Qualified to AEC Q101

Applications

- Automotive Engine Control
- Powertrain Management
- Solenoid and Motor Drivers
- Integrated Starter/alternator
- Primary Switch for 12V Systems





For current package drawing, please refer to the Fairchild website at www.fairchildsemi.com/packaging

MOSFET Maximum Ratings T_{.1} = 25°C unless otherwise noted

Symbol	Parameter		Ratings	Units
V_{DSS}	Drain to Source Voltage		150	V
V_{GS}	Gate to Source Voltage	±20	V	
	Drain Current - Continuous (V_{GS} =10) (Note 1) T_C = 25°C Pulsed Drain Current T_C = 25°C		169	А
'D			See Figure4	7 ^
E _{AS}	Single Pulse Avalanche Energy	(Note 2)	502	mJ
D	Power Dissipation		500	W
P_{D}	Derate above 25°C		3.3	W/°C
T _J , T _{STG}	Operating and Storage Temperature		-55 to + 175	°C
$R_{\theta JC}$	Thermal Resistance Junction to Case		0.3	°C/W
$R_{\theta JA}$	Maximum Thermal Resistance Junction to Ambient (Note 3)		43	°C/W

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDBL86210	FDBL86210_F085	MO-299A	-	-	-

Notes

- 1: Current is limited by junction temperature.
- 2: Starting $T_J = 25^{\circ}C$, L = 0.24mH, $I_{AS} = 64$ A, $V_{DD} = 100$ V during inductor charging and $V_{DD} = 0$ V during time in avalanche 3: $R_{\theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder
- 3: $R_{\theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. $R_{\theta JC}$ is guaranteed by design while $R_{\theta JA}$ is determined by the user's board design. The maximum rating presented here is based on mounting on a 1 in² pad of 2oz copper.

Units

nΑ

Max

±100

Тур

Electrical Characteristics $T_J = 25^{\circ}C$ unless otherwise noted

Parameter

Gate to Source Leakage Current

Off Characteristics							
B_{VDSS}	Drain to Source Breakdown Voltage	I _D = 250μA, \	_{GS} = 0V	150	-	-	V
	Drain to Source Leakage Current	V _{DS} =150V,	$T_J = 25^{\circ}C$	-	-	1	μА
IDSS	Diam to Source Leakage Current	$V_{GS} = 0V$	$T_{.1} = 175^{\circ}C(Note 4)$	-	-	1	mA

 $V_{GS} = \pm 20V$

Test Conditions

Min

On Characteristics

Symbol

 I_{GSS}

$V_{GS(th)}$	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_D = 250 \mu A$		2.0	2.8	4.0	V
r _{DS(on)} Drain to Source On Resistance	I _D = 80A,	$T_{J} = 25^{\circ}C$	-	5	6.3	$m\Omega$	
DS(on)	r _{DS(on)} Drain to Source On Resistance	V _{GS} = 10V	$T_J = 175^{\circ}C(Note 4)$	-	14	17.5	mΩ

Dynamic Characteristics

C _{iss}	Input Capacitance	75/// 0//		-	5805	-	pF
C _{oss}	Output Capacitance	- ν _{DS} = 75ν, ν _{GS} = ι - f = 1MHz	$V_{DS} = 75V, V_{GS} = 0V,$		536	-	pF
C _{rss}	Reverse Transfer Capacitance	-1 - 1WITZ		-	16	-	pF
R_g	Gate Resistance	f = 1MHz		-	2.2	-	Ω
$Q_{g(ToT)}$	Total Gate Charge at 10V	V_{GS} = 0 to 10V	V _{DD} = 75V	-	70	90	nC
$Q_{g(th)}$	Threshold Gate Charge	$V_{GS} = 0$ to 2V	I _D = 80A	-	10.5	13	nC
Q_{gs}	Gate to Source Gate Charge		_	-	32.5	-	nC
Q_{gd}	Gate to Drain "Miller" Charge			-	10	-	nC

Switching Characteristics

t _{on}	Turn-On Time		-	-	80	ns
t _{d(on)}	Turn-On Delay Time		-	39	-	ns
t _r	Rise Time	V _{DD} = 75V, I _D = 80A,	-	30	-	ns
t _{d(off)}	Turn-Off Delay Time	V_{GS} = 10V, R_{GEN} = 6Ω	-	70	-	ns
t _f	Fall Time		-	23	-	ns
t _{off}	Turn-Off Time		-	-	130	ns

Drain-Source Diode Characteristics

V _{SD} Source to Drain Diode Voltage	Source to Drain Diode Voltage	I _{SD} =80A, V _{GS} = 0V	-	-	1.25	V
	I_{SD} = 40A, V_{GS} = 0V	-	-	1.2	V	
T _{rr}	Reverse Recovery Time	$I_F = 80A$, $dI_{SD}/dt = 100A/\mu s$,	-	108	125	ns
Q _{rr}	Reverse Recovery Charge	V _{DD} =120V	-	323	467	nC

Notes:

4: The maximum value is specified by design at T_J = 175°C. Product is not tested to this condition in production.

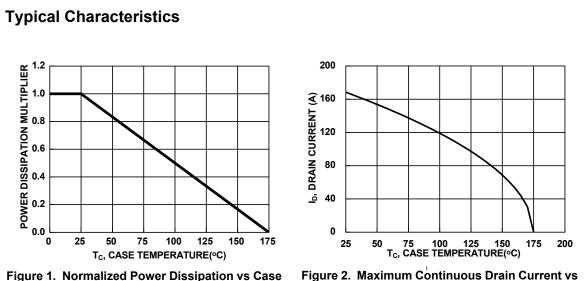
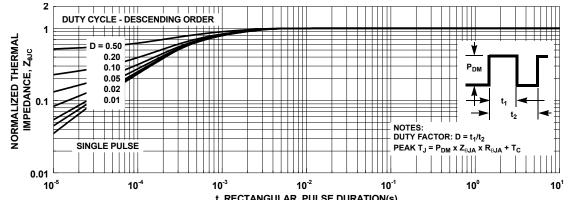


Figure 1. Normalized Power Dissipation vs Case Temperature

Figure 2. Maximum Continuous Drain Current vs
Case Temperature



t, RECTANGULAR PULSE DURATION(s)
Figure 3. Normalized Maximum Transient Thermal Impedance

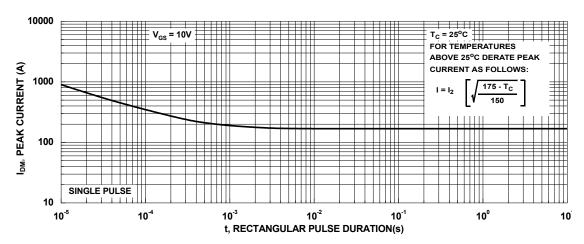


Figure 4. Peak Current Capability

Typical Characteristics

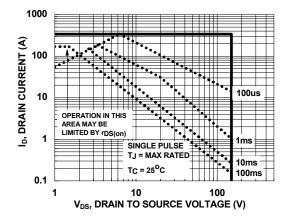
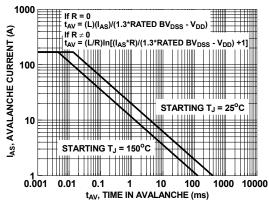


Figure 5. Forward Bias Safe Operating Area



NOTE: Refer to Fairchild Application Notes AN7514 and AN7515

Figure 6. Unclamped Inductive Switching

Capability

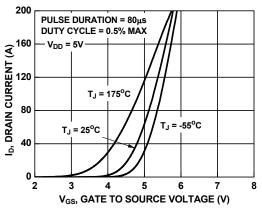


Figure 7. Transfer Characteristics

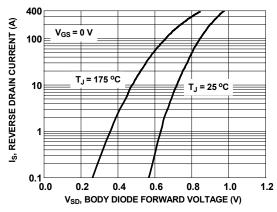


Figure 8. Forward Diode Characteristics

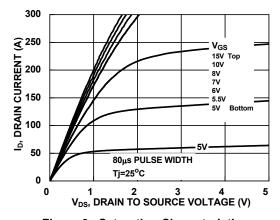


Figure 9. Saturation Characteristics

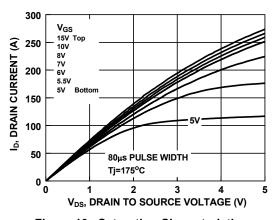


Figure 10. Saturation Characteristics

Typical Characteristics

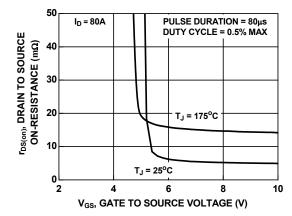


Figure 11. Rdson vs Gate Voltage

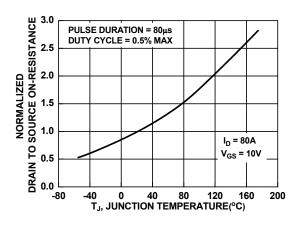


Figure 12. Normalized Rdson vs Junction Temperature

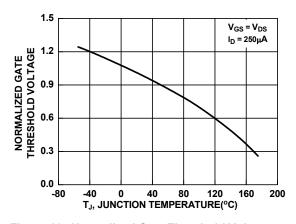


Figure 13. Normalized Gate Threshold Voltage vs Temperature

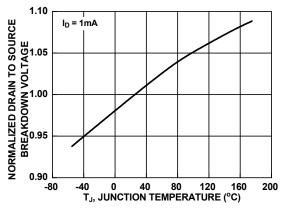


Figure 14. Normalized Drain to Source Breakdown Voltage vs Junction Temperature

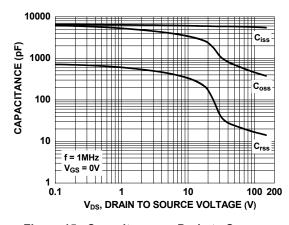


Figure 15. Capacitance vs Drain to Source Voltage

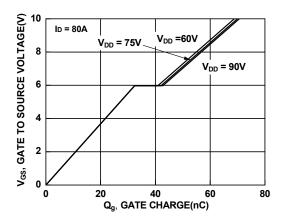


Figure 16. Gate Charge vs Gate to Source Voltage





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